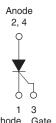
Vishay Semiconductors

Thyristor Surface Mount, Phase Control SCR, 8 A



www.vishay.com



TO-263AB (D²PAK)

| | ٦ |
|--------|------|
| 1 | 3 |
| athode | Gate |

| PRODUCT SUMMARY | | | | | |
|------------------------------------|-------------------------------|--|--|--|--|
| Package | TO-263AB (D ² PAK) | | | | |
| Diode variation | Single SCR | | | | |
| I _{T(AV)} | 8 A | | | | |
| V _{DRM} /V _{RRM} | 800 V | | | | |
| V _{TM} | 1.2 V | | | | |
| I _{GT} | 15 mA | | | | |
| TJ | -40 to +125 °C | | | | |

FEATURES

- J-STD-020, Meets MSL level 1, per LF maximum peak of 260 °C
- Designed and qualified according JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Input rectification and crow-bar (soft start)
- · Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-12TTS08S-M3 High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

| OUTPUT CURRENT IN TYPICAL APPLICATIONS | | | | | | |
|---|---------------------|--------------------|-------|--|--|--|
| APPLICATIONS | SINGLE-PHASE BRIDGE | THREE-PHASE BRIDGE | UNITS | | | |
| Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$, common heatsink of 1 °C/W | 13.5 | 17 | A | | | |

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|------------------------------------|-----------------------------|-------------|-------|--|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | | |
| I _{T(AV)} | Sinusoidal waveform | 8 | A | | | |
| I _{T(RMS)} | | 12.5 | A | | | |
| V _{RRM} /V _{DRM} | | 800 | V | | | |
| I _{TSM} | | 110 | А | | | |
| V _T | 8 A, T _J = 25 °C | 1.2 | V | | | |
| dV/dt | | 150 | V/µs | | | |
| dl/dt | | 100 | A/µs | | | |
| TJ | Range | -40 to +125 | °C | | | |

| VOLTAGE RATINGS | | | |
|-----------------|---|--|---|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V | I _{RRM} ∕I _{DRM} AT 125 °C mA |
| VS-12TTS08S-M3 | 800 | 800 | 1.0 |

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| PARAMETER | SYMBOL | | TEST CONDITIONS | | |
|--|----------------------------------|--|---|------------------|------|
| Maximum average on-state current | I _{T(AV)} | T 100 %O | | 8 | |
| Maximum RMS on-state current | I _{T(RMS)} | $T_{\rm C} = 108^{-5}$ C, | 180° conduction, half sine wave | 12.5 | • |
| Maximum peak one-cycle | | 10 ms sine pu | llse, rated V_{RRM} applied, $T_J = 125 \ ^{\circ}C$ | 95 | A |
| non-repetitive surge current | I _{TSM} | 10 ms sine pu | ilse, no voltage reapplied, $T_J = 125 \text{ °C}$ | 110 | |
| Maximum 12t for fusing | l ² t | 10 ms sine pu | ilse, rated V_{RRM} applied, $T_J = 125 \text{ °C}$ | 45 | A2a |
| Maximum I ² t for fusing | 1-1 | 10 ms sine pu | 64 | A ² s | |
| Maximum $I^2 \sqrt{t}$ for fusing | l²√t | t = 0.1 ms to 7 | t = 0.1 ms to 10 ms, no voltage reapplied, T_J = 125 °C | | |
| Maximum on-state voltage drop | V _{TM} | 8 A, T _J = 25 °C | | 1.2 | V |
| On-state slope resistance | r _t | T 105.00 | | 16.2 | mΩ |
| Threshold voltage | V _{T(TO)} | T _J = 125 °C | | 0.87 | V |
| | 1 /1 | T _J = 25 °C | | 0.05 | |
| Maximum reverse and direct leakage current | I _{RM} /I _{DM} | T _J = 125 °C | $V_{R} = Rated V_{RRM}/V_{DRM}$ | 1.0 | |
| Typical holding current | Ι _Η | Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C | | 30 | mA |
| Maximum latching current | ١ _L | Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$ | | 50 | |
| Maximum rate of rise of off-state voltage | dV/dt | $T_J = T_J max.,$ | linear to 80 %, $V_{DRM} = R_g - k = Open$ | 150 | V/µs |
| Maximum rate of rise of turned-on current | dl/dt | | | 100 | A/µs |

| TRIGGERING | | | | | | |
|---|--------------------|---|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum peak gate power | P _{GM} | | 8.0 | W | | |
| Maximum average gate power | P _{G(AV)} | | 2.0 | vv | | |
| Maximum peak positive gate current | + I _{GM} | | 1.5 | А | | |
| Maximum peak negative gate voltage | - V _{GM} | | 10 | V | | |
| | | Anode supply = 6 V, resistive load, T_J = - 65 °C | 20 | | | |
| Maximum required DC gate current to trigger | I _{GT} | Anode supply = 6 V, resistive load, $T_J = 25 \ ^{\circ}C$ | 15 | mA | | |
| | | Anode supply = 6 V, resistive load, T_J = 125 °C | 10 | | | |
| | | Anode supply = 6 V, resistive load, T_J = - 65 °C | 1.2 | | | |
| Maximum required DC gate voltage to trigger | V _{GT} | Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$ | 1 | N/ | | |
| | | Anode supply = 6 V, resistive load, T_J = 125 °C | 0.7 | V | | |
| Maximum DC gate voltage not to trigger | V_{GD} | T 125 °C V Batad value | 0.2 | | | |
| Maximum DC gate current not to trigger | I _{GD} | T _J = 125 °C, V _{DRM} = Rated value 0.1 | | mA | | |

| SWITCHING | | | | | | |
|-------------------------------|-----------------|-------------------------|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Typical turn-on time | t _{gt} | T _J = 25 °C | 0.8 | | | |
| Typical reverse recovery time | t _{rr} | T 125 °C | 3 | μs | | |
| Typical turn-off time | tq | T _J = 125 °C | 100 | | | |

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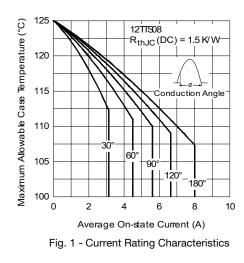
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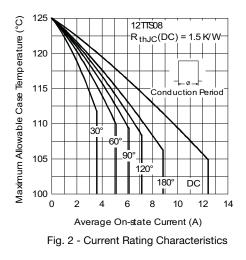


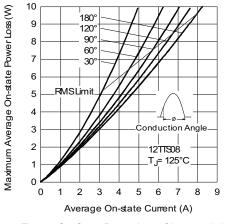
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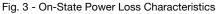
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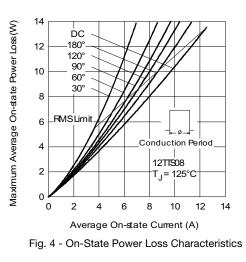
| THERMAL AND ME | THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|--|---------------------------------------|-----------------------------------|---|-------------|------------|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction and sto temperature range | rage | T _J , T _{Stg} | | -40 to +125 | °C | | |
| Maximum thermal resistan junction to case | ce, | R _{thJC} | DC operation | 1.5 | | | |
| Maximum thermal resistan junction to ambient | ce, | R _{thJA} | | 62 | °C/W | | |
| Typical thermal resistance case to heatsink | , | R _{thCS} | Mounting surface, smooth and greased | 0.5 | | | |
| Approvimente weight | | | | 2 | g | | |
| Approximate weight | | | | 0.07 | oz. | | |
| Mounting torque | minimum | | | 6 (5) | kgf ⋅ cm | | |
| Mounting torque – | maximum | | | 12 (10) | (lbf · in) | | |
| Marking device | | | Case style D ² PAK (SMD-220) | 12TT | S08S | | |











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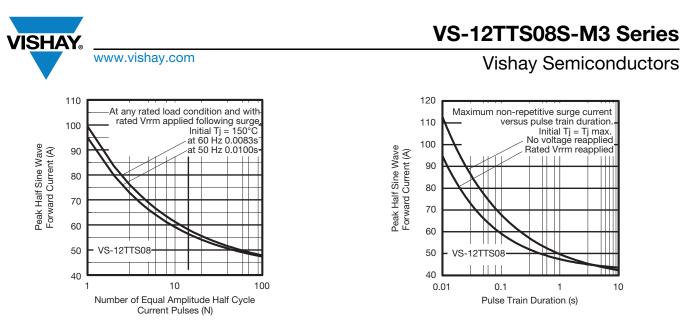
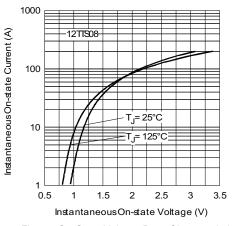


Fig. 5 - Maximum Non-Repetitive Surge Current

Fig. 6 - Maximum Non-Repetitive Surge Current





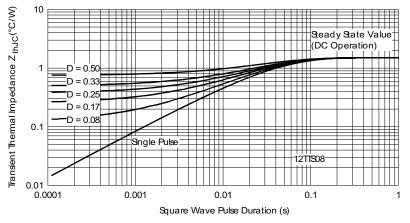


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

VS-12TTS08S-M3 Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

| Device code | VS- | 12 | т | т | s | 08 | S | TRL | -M3 |
|-------------|-----|--------|--------------------|-----------|-----------|-----------|----------|-----------|-----------|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 |
| | 1 | - Visl | hay Sen | nicondu | ctors pro | oduct | | | |
| | 2 · | - Cur | rent rati | ng (12.5 | 5 A) | | | | |
| | 3 · | - Circ | cuit conf | iguratior | า: | | | | |
| | | T = | Single t | hyristor | | | | | |
| | 4 | | kage: | | | | | | |
| | | T = | D ² PAK | | | | | | |
| | 5. | - Тур | e of silio | con: | | | | | |
| | | S = | Standa | rd recov | ery rect | ifier | | | |
| | 6 | - Vol | tage rati | ng (08 = | = 800 V) |) | | | |
| | 7 - | S = | Surface | e mounta | able | | | | |
| | 8 - | • No | one = Ti | ube | | | | | |
| | | • TF | RL = Tap | be and re | eel (left | orienteo | d) | | |
| | | • TF | RR = Ta | pe and r | eel (righ | nt orient | ed) | | |
| | 9 - | -M3 | = Halo | gen-free | , RoHS | -complia | ant, and | l termina | ations le |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-12TTS08S-M3 | 50 | 1000 | Antistatic plastic tubes | | | | |
| VS-12TTS08STRR-M3 | 800 | 800 | 13" diameter reel | | | | |
| VS-12TTS08STRL-M3 | 800 | 800 | 13" diameter reel | | | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|-------------------------------------|--------------------------|--|--|--|
| Dimensions www.vishay.com/doc?95046 | | | | |
| Part marking information | www.vishay.com/doc?95444 | | | |
| Packaging information | www.vishay.com/doc?95032 | | | |



Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SHA



| SYMBOL | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES |
|--------|-------------|-------|--------|-------|-------|---------|-------------|-------|-----------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. | NOTES | STINDUL | MIN. | MAX. | MIN. | MAX. | NULES |
| A | 4.06 | 4.83 | 0.160 | 0.190 | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | е | 2.54 BSC | | 0.100 BSC | | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | L3 | 0.25 BSC | | 0.010 BSC | | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

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